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AMENDMENTS TO THE CLAIMS

- 1-98 (Canceled)
- 99. (Currently amended) A composition comprising:

a substrate;

an array of nanostructured silicon columns defining a three-dimensional surface and an interface with a void volume, said array of nanostructured silicon columns extending from said surface, each of said array of nanostructured silicon columns having a width of between 20 and 30 nanometers;

a plurality of metallic nanocrystals spaced uniformly between columns of said array of nanostructured silicon columns, said plurality of metallic nanocrystals exhibiting surface plasmon resonance.

- 100. (Previously presented) The composition of claim 99 wherein said substrate is planar glass.
- 101. (Previously presented) The composition of claim 99 wherein said array of nanostructured silicon columns have an average columnar separation of 20 nanometers.
- 102. (Currently amended) The composition of claim 99 wherein said array of nanostructured silicon columns has a height of less than 2000 Angstroms and a columnar width of 20 to 30 nanometers.

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103. (Previously presented) The composition of claim 99 wherein the three-

dimensional surface has an oxide layer underlying said plurality of metallic nanocrystals.

104. (Previously presented) The composition of claim 99 wherein said plurality of

metallic nanocrystals are formed from the element of silver, gold, copper, iron, palladium, or

platinum.

105. (Previously presented) The composition of claim 99 wherein one of said plurality

of metallic nanocrystals bridges two spatially separated adjacent columns of said array of

nanostructured silicon columns.

106. (Canceled)

107. (Currently amended) A composition comprising:

a substrate;

an array of nanostructured semiconductor columns defining a three-dimensional surface

and an interface with a void volume and extending from said surface with an average separation

between adjacent columns of said array of nanostructured semiconductor columns;

a plurality of metallic nanocrystals where a single nanocrystal of said plurality of metallic

nanocrystals bridges two spatially separated adjacent columns of said array of nanostructured

semiconductor columns, said plurality of metallic nanocrystals exhibiting surface plasmon

resonance.

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108. (Previously presented) The composition of claim 107 wherein said array of

nanostructured silicon columns have an average columnar separation of 20 nanometers.

109. (Previously presented) The composition of claim 107 wherein the three-

dimensional surface has an oxide layer underlying said plurality of metallic nanocrystals.

110. (Previously presented) The composition of claim 107 wherein said plurality of

metallic nanocrystals are formed from the element of silver, gold, copper, iron, palladium, or

platinum.

111-115 (Canceled)